DISCRETE SEMICONDUCTORS

DATA SHEET

BFG94NPN 6 GHz wideband transistor

Product specification

September 1995



BFG94

FEATURES

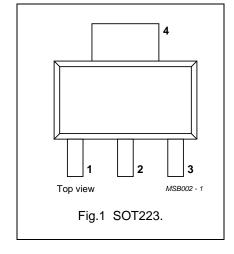
- High power gain
- Low noise figure
- Low intermodulation distortion
- Gold metallization ensures excellent reliability.

DESCRIPTION

NPN transistor mounted in a plastic SOT223 envelope. It is primarily intended for use in communication and instrumentation systems.

PINNING

PIN	DESCRIPTION	
1	emitter	
2	base	
3	emitter	
4	collector	



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	_	15	V
V_{CEO}	collector-emitter voltage	open base	_	_	12	V
I _C	DC collector current		_	_	60	mA
P _{tot}	total power dissipation	up to $T_s = 140 ^{\circ}\text{C}$ (note 1)	_	_	700	mW
C_{re}	feedback capacitance	I _C = 0; V _{CE} = 10 V; f = 1 MHz	_	_	0.8	pF
f _T	transition frequency	I_C = 45 mA; V_{CE} = 10 V; f = 1 GHz; T_{amb} = 25 °C	4	6	_	GHz
G _{UM}	maximum unilateral power gain	$I_C = 45 \text{ mA}; V_{CE} = 10 \text{ V}; f = 1 \text{ GHz};$ $T_{amb} = 25 \text{ °C}$	11.5	13.5	_	dB
Vo	output voltage	I_{C} = 45 mA; V_{CE} = 10 V; d_{im} = -60 dB; R_{L} = 75 Ω ; f = 800 MHz; T_{amb} = 25 °C	_	500	_	mV
P _{L1}	output power at 1 dB gain compression	$I_C = 45 \text{ mA}; V_{CE} = 10 \text{ V}; f = 1 \text{ GHz}; T_{amb} = 25 ^{\circ}C$	_	21.5	_	dBm

Note

1. T_s is the temperature at the soldering point of the collector tab.

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LIMITING VALUES

In accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	15	V
V_{CEO}	collector-emitter voltage	open base	_	12	V
V _{EBO}	emitter-base voltage	open collector	_	2	V
I _C	DC collector current		_	60	mA
P _{tot}	total power dissipation	up to T _s = 140 °C (note 1)	_	700	mW
T _{stg}	storage temperature		-65	150	°C
Tj	junction temperature		_	175	°C

THERMAL RESISTANCE

SYMBOL	PARAMETER	CONDITIONS	THERMAL RESISTANCE
, 0	thermal resistance from junction to soldering point	up to $T_s = 140 ^{\circ}\text{C}$ (note 1)	50 K/W

Note

1. T_s is the temperature at the soldering point of the collector tab.

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CHARACTERISTICS

T_i = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector cut-off current	I _E = 0; V _{CB} = 10 V	_	_	100	nA
h _{FE}	DC current gain	I _C = 30 mA; V _{CE} = 5 V	45	90	_	
		$I_C = 45 \text{ mA}; V_{CE} = 10 \text{ V}$	_	100	_	
C _c	collector capacitance	$I_E = i_e = 0$; $V_{CB} = 10 \text{ V}$; $f = 1 \text{ MHz}$	_	0.9	2	pF
C _e	emitter capacitance	$I_C = i_e = 0$; $V_{EB} = 0.5 \text{ V}$; $f = 1 \text{ MHz}$	_	2.9	4.5	pF
C _{re}	feedback capacitance	$I_C = i_c = 0$; $V_{CE} = 10 \text{ V}$; $f = 1 \text{ MHz}$	_	0.5	0.8	pF
f _T	transition frequency	$I_C = 45 \text{ mA}; V_{CE} = 10 \text{ V}; f = 1 \text{ GHz}; T_{amb} = 25 ^{\circ}C$	4	_	_	GHz
		$I_C = 30 \text{ mA}; V_{CE} = 5 \text{ V}; f = 1 \text{ GHz}; T_{amb} = 25 ^{\circ}\text{C}$	4	6	_	GHz
G _{UM}	maximum unilateral power gain (note1)	$I_C = 45 \text{ mA}; V_{CE} = 10 \text{ V}; f = 1 \text{ GHz}; T_{amb} = 25 ^{\circ}C$	11.5	13.5	_	dB
F	minimum noise figure	$\Gamma_{\text{S}} = \Gamma_{\text{opt}}$; $I_{\text{C}} = 45 \text{ mA}$; $V_{\text{CE}} = 10 \text{ V}$; $f = 500 \text{ MHz}$	_	2.7	_	dB
		$\Gamma_{\text{S}} = \Gamma_{\text{opt}}; I_{\text{C}} = 45 \text{ mA}; \ V_{\text{CE}} = 10 \text{ V}; \ f = 1 \text{ GHz}$	_	3	-	dB
Vo	output voltage	note 2	_	500	_	mV
d ₂	second order intermodulation distortion	note 3	_	-51	_	dB
P _{L1}	output power at 1 dB gain compression	I_C = 45 mA; V_{CE} = 10 V; R_L = 50 Ω ; T_{amb} = 25 °C; measured at f = 1 GHz	_	21.5	_	dBm
ITO	third order intercept point	note 4		34	_	dBm

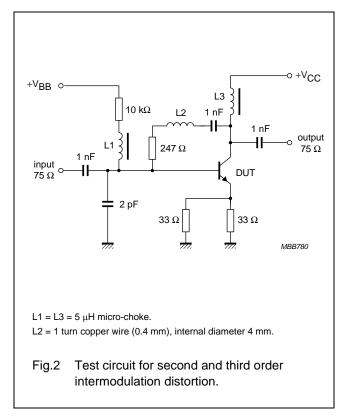
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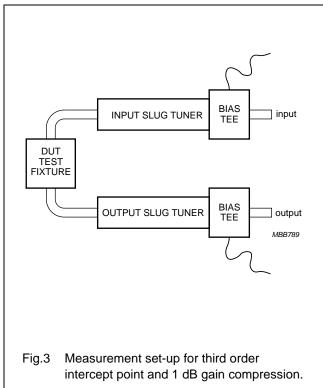
1. G_{UM} is the maximum unilateral power gain, assuming S_{12} is zero and

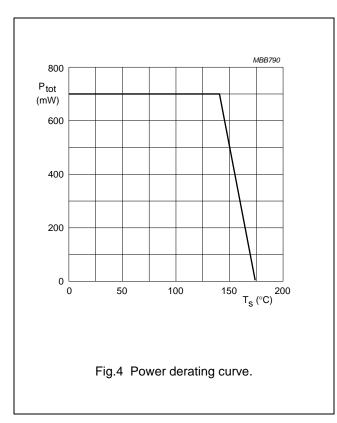
$$G_{UM} = 10 \log \frac{\left|S_{21}\right|^2}{(1 - \left|S_{11}\right|^2)(1 - \left|S_{22}\right|^2)} dB.$$

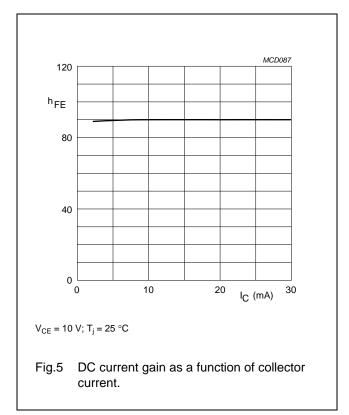
- 2. $d_{im} = -60 \text{ dB (DIN } 45004 \text{B, par } 6.3\text{: } 3\text{-tone)}; I_C = 45 \text{ mA; } V_{CE} = 10 \text{ V; } R_L = 75 \Omega; T_{amb} = 25 ^{\circ}C;$ $V_p = V_O$ at $d_{im} = -60$ dB; $f_p = 795.25$ MHz;

 - $V_{q} = V_{O} 6 \text{ dB}; V_{r} = V_{O} 6 \text{ dB};$
 - $f_{\alpha} = 803.25 \text{ MHz}$; $f_{r} = 805.25 \text{ MHz}$;
 - measured at $f_{(p+q-r)} = 793.25$ MHz.
- 3. $I_C = 45$ mA; $V_{CE} = 10$ V; $R_L = 75$ Ω ; $T_{amb} = 25$ °C;
 - $V_q = V_O = 280 \text{ mV};$
 - $f_p = 250 \text{ MHz}; f_q = 560 \text{ MHz};$
 - measured at $f_{(p+q)} = 810 \text{ MHz}$.
- 4. I_C = 45 mA; V_{CE} = 10 V; R_L = 50 Ω ; T_{amb} = 25 °C;
 - $f_p = 1000 \text{ MHz}; f_q = 1001 \text{ MHz};$
 - measured at $f_{(2p-q)}$ and $f_{(2q-p)}$.









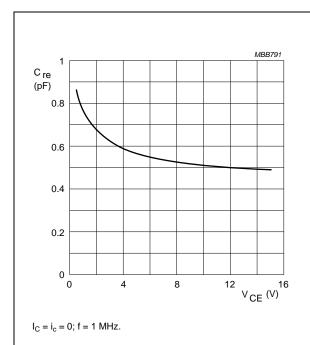


Fig.6 Feedback capacitance as a function of collector-emitter voltage.

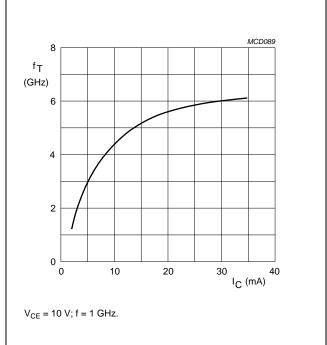
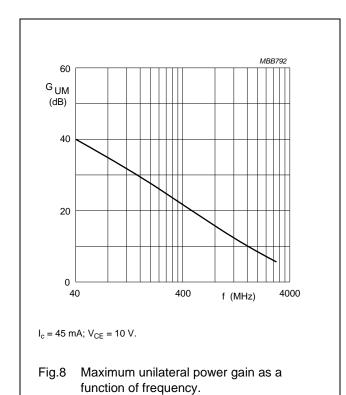
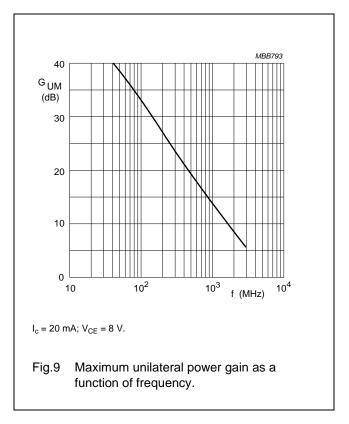


Fig.7 Transition frequency as a function of collector current.

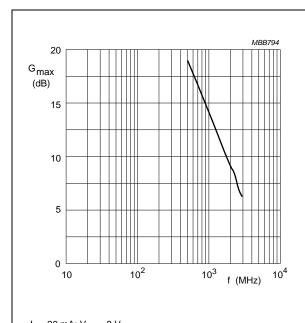




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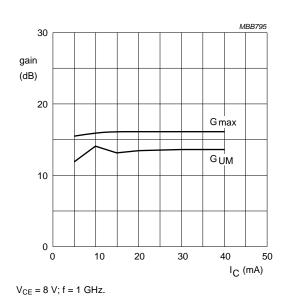
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 $I_c = 20 \text{ mA}; V_{CE} = 8 \text{ V}.$

Fig.10 Maximum available stable gain as a function of frequency.



G_{max} = maximum available stable gain.

G_{UM} = maximum unilateral power gain.

Fig.11 Gain as a function of collector current.

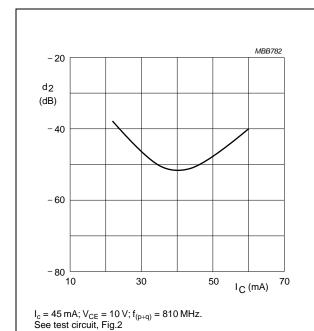


Fig.12 Second order intermodulation distortion as a function of collector current.

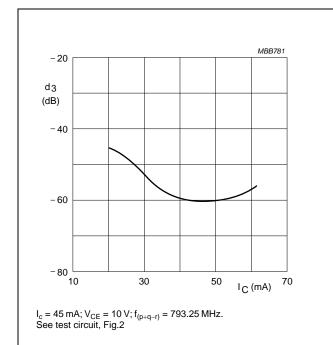
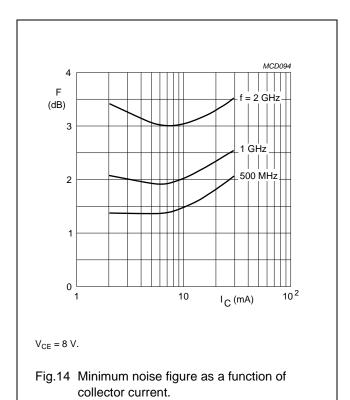
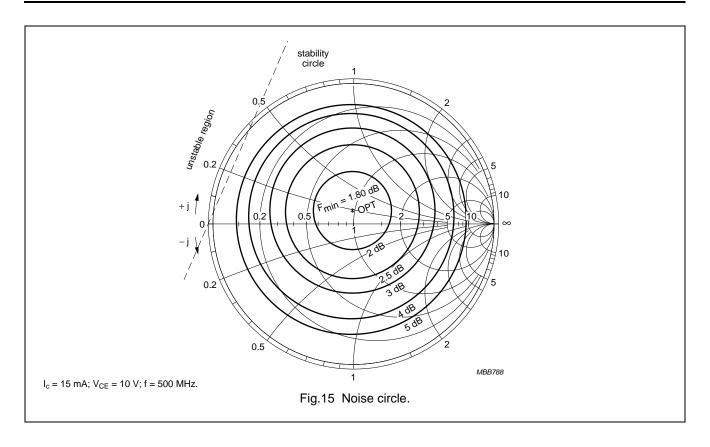
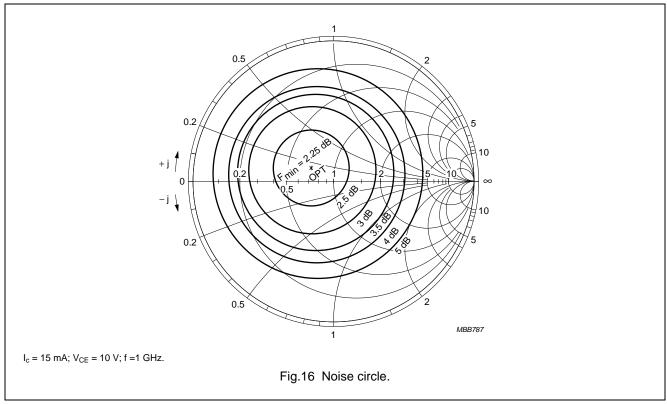


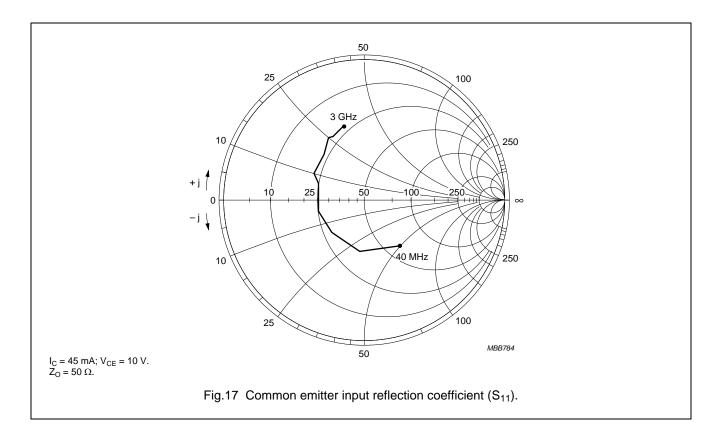
Fig.13 Third order intermodulation distortion as a function of collector current.

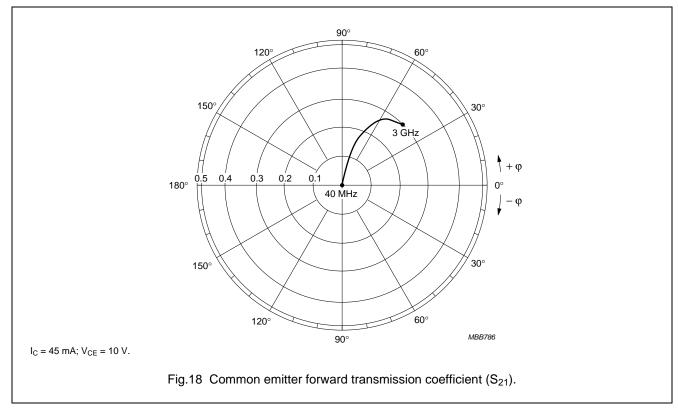


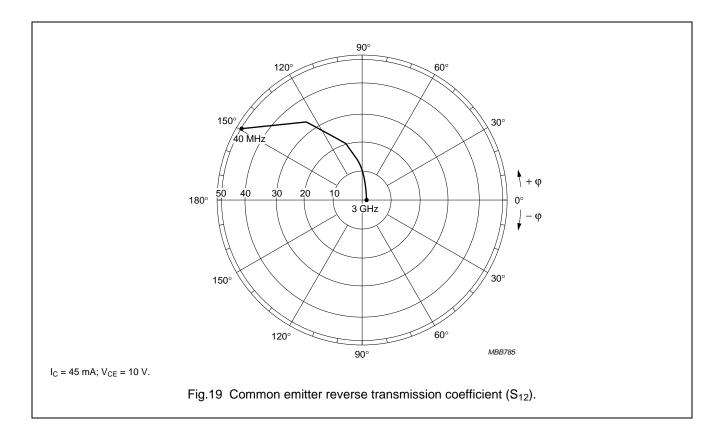
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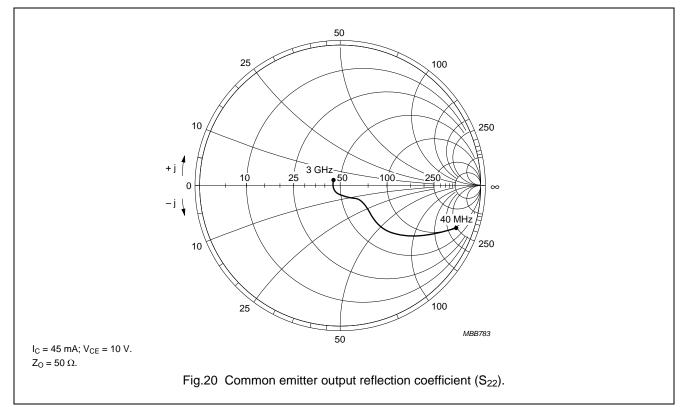










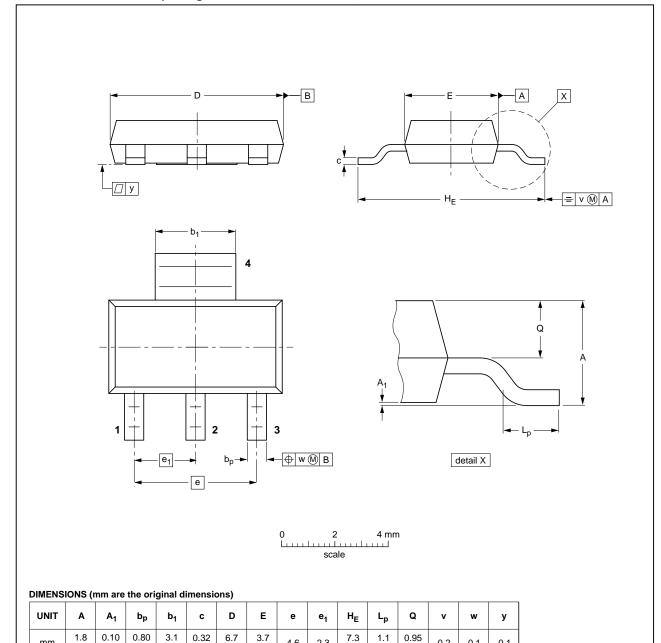


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PACKAGE OUTLINE

Plastic surface-mounted package with increased heatsink; 4 leads

SOT223



OUTLINE		REFERENCES			EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT223			SC-73			04-11-10 06-03-16

2.3

0.2

0.1

4.6

0.01

0.60

2.9

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DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

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